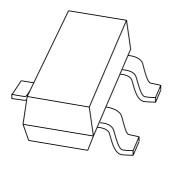
DISCRETE SEMICONDUCTORS

DATA SHEET



BAT17Schottky barrier diode

Product specification Supersedes data of 1999 May 26 2003 Mar 25





Schottky barrier diode

BAT17

FEATURES

- · Low forward voltage
- Small SMD package
- · Low capacitance.

APPLICATIONS

- UHF mixer
- · Sampling circuits
- Modulators
- Phase detection.

DESCRIPTION

Planar Schottky barrier diode in a small SOT23 plastic SMD package.

MARKING

TYPE NUMBER	MARKING CODE ⁽¹⁾
BAT17	A3*

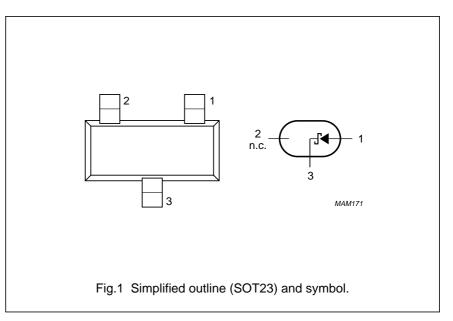
Note

* = p : Made in Hong Kong.
 * = t : Made in Malaysia.

* = W : Made in China.

PINNING

PIN	DESCRIPTION				
1	anode				
2	not connected				
3	cathode				



LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
V _R	continuous reverse voltage	_	4	V
I _F	continuous forward current	_	30	mA
T _{stg}	storage temperature	-65	+150	°C
Tj	junction temperature	_	100	°C

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ELECTRICAL CHARACTERISTICS

 T_{amb} = 25 °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MAX.	UNIT
V _F	forward voltage	see Fig.2		
		I _F = 0.1 mA	350	mV
		I _F = 1 mA	450	mV
		I _F = 10 mA	600	mV
I _R	reverse current	V _R = 3 V; see Fig.3	0.25	μΑ
		V _R = 3 V; T _{amb} = 60 °C; see Fig.3	1.25	μΑ
r_D	diode forward resistance	$f = 1 \text{ kHz}; I_F = 5 \text{ mA}$	15	Ω
C _d	diode capacitance	$f = 1 \text{ MHz}$; $V_R = 0$; see Fig.4	1	pF
F	noise figure	f = 900 MHz; note 1	8	dB

Note

1. The local oscillator is adjusted for a diode current of 2 mA. IF amplifier noise F_{if} = 1.5 dB; f = 35 MHz.

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R _{th j-a}	thermal resistance from junction to ambient	note 1	500	K/W

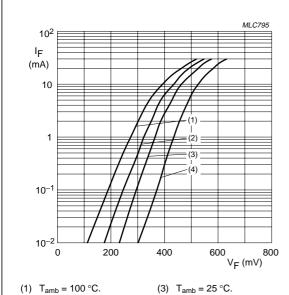
Note

1. Refer to SOT23 standard mounting conditions.

Schottky barrier diode

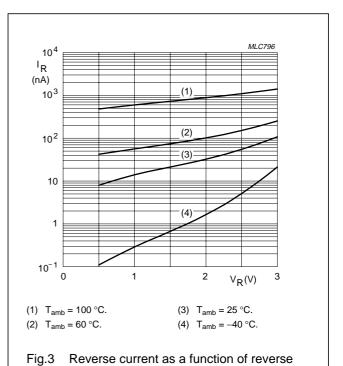
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GRAPHICAL DATA

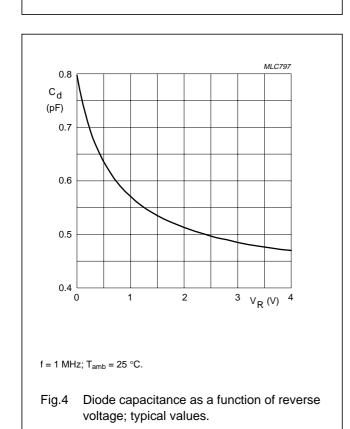


- (3) $T_{amb} = 25 \,^{\circ}C$.
- (2) $T_{amb} = 60 \, ^{\circ}C$. (4) $T_{amb} = -40 \,^{\circ}C$.

Fig.2 Forward current as a function of forward voltage; typical values.



voltage; typical values.



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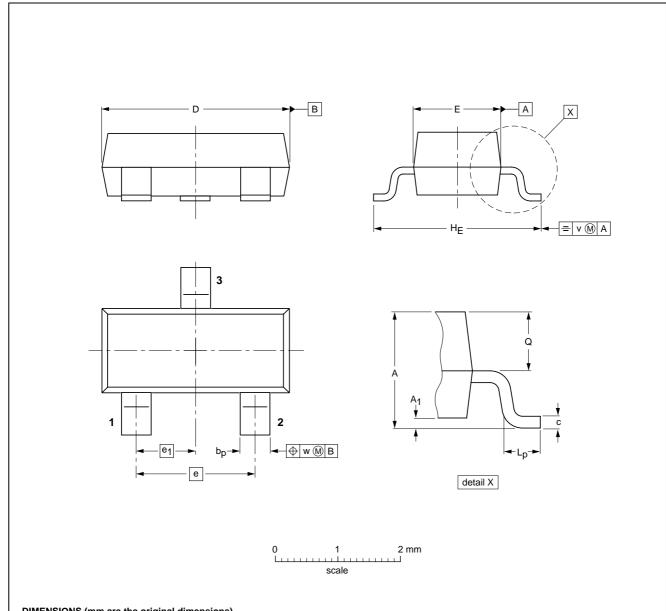
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PACKAGE OUTLINE

Plastic surface mounted package; 3 leads

SOT23



DIMENS	10N2 (II	im are ti	ne origir	iai dime	nsions)	
						ī

UNIT	A	A ₁ max.	bp	С	D	E	е	e ₁	HE	L _p	Q	v	w
mm	1.1 0.9	0.1	0.48 0.38	0.15 0.09	3.0 2.8	1.4 1.2	1.9	0.95	2.5 2.1	0.45 0.15	0.55 0.45	0.2	0.1

OUTLINE	TLINE REFERENCES					ISSUE DATE	
VERSION	IEC	JEDEC	EIAJ		PROJECTION	ISSUE DATE	
SOT23		TO-236AB				-97-02-28- 99-09-13	

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DATA SHEET STATUS

LEVEL	DATA SHEET STATUS ⁽¹⁾	PRODUCT STATUS(2)(3)	DEFINITION
I	Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
II	Preliminary data	Qualification	This data sheet contains data from the preliminary specification. Supplementary data will be published at a later date. Philips Semiconductors reserves the right to change the specification without notice, in order to improve the design and supply the best possible product.
III	Product data	Production	This data sheet contains data from the product specification. Philips Semiconductors reserves the right to make changes at any time in order to improve the design, manufacturing and supply. Relevant changes will be communicated via a Customer Product/Process Change Notification (CPCN).

Notes

- 1. Please consult the most recently issued data sheet before initiating or completing a design.
- 2. The product status of the device(s) described in this data sheet may have changed since this data sheet was published. The latest information is available on the Internet at URL http://www.semiconductors.philips.com.
- 3. For data sheets describing multiple type numbers, the highest-level product status determines the data sheet status.

DEFINITIONS

Short-form specification — The data in a short-form specification is extracted from a full data sheet with the same type number and title. For detailed information see the relevant data sheet or data handbook.

Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 60134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

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NOTES

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Contact information

For additional information please visit http://www.semiconductors.philips.com. Fax: +31 40 27 24825 For sales offices addresses send e-mail to: sales.addresses@www.semiconductors.philips.com.

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